

Current Sensor

Product Series: STK-PL

STK-10PL,

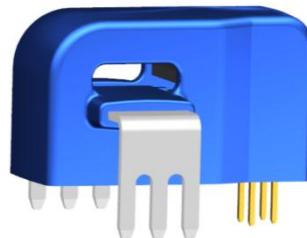
STK-16PL,

STK-20PL,

STK-32PL,

Part number: STK-40PL,
STK-50PL,
STK-50PL/R

Version: Ver6.3



Sinomags Technology Co., Ltd

Web site: www.sinomags.com

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1. Summary

The STK-PL series is based on TMR (Tunneling-Magnetoresistance) technology and open-loop design. It is suitable for DC, AC, pulsed and any kind of irregular current measurement under the isolated conditions. The nominal current range of the STK-PL current sensor consists of 10 A, 16 A, 20 A, 32 A, 40 A, 50 A.

Typical applications

- PV combiner box
- PV inverter (MPPT & AC)
- motor driver controller
- SMPS & UPS
- Battery management system

Standards

- EN50178:1997
- IEC 61010-1:2010
- IEC 61326-1:2012

General parameter

Parameter	Symbol	Unit	Value
Working temperature	T_A	°C	-40 ~ 105
Storage temperature	T_stg	°C	-40 ~ 105
Mass	m	g	10

Absolute maximum rating

Parameter	Symbol	Unit	Value
Supply voltage (non-destructive)	V_C	V	6.0
ESD rating (HBM)	U_ESD	kV	4
ESD rating (CDM)	U_CDM	kV	1.5
High temperature and humidity	T_HAST	-	85°C&85%RH (1000h)

Remark: the unrecoverable damage may occur when the product works on the conditions over the absolute maximum ratings. Long-time working on the absolute maximum ratings may cause the degradation on performance and reliability.

Ratings

Parameter	Symbol	Unit	Value
Primary involved potential		V AC/DC	600
Ambient operating temperature	T_A	°C	105
Primary current	I_p	A	According to series primary current
Secondary supply voltage	U_c	V DC	5
Output voltage	V_out	V	0.1 ~ 4.9

Isolation parameter

Parameter	Symbol	Unit	Value	Comment
RMS voltage for AC test 50Hz/1 min	Ud	kV	5	
Impulse withstand voltage 1.2/50μs	Üw	kV	8	
Clearance distance (pri. -sec)	dCl	mm	8	Shortest distance through air
Creepage distance (pri. -sec)	dCp	mm	8	Shortest path along device body
Case material			V0 according to UL 94	
Application example		V	600	Reinforced insulation, CAT III, PD 2, non uniform field according EN 50178, IEC 61010
Application example		V	1000	Basic insulation, CAT III, PD 2, non uniform field according EN 50178, IEC 61010
Application example		V	1500	Basic insulation, CAT III, PD 2, according to IEC 62109-1 Altitude ≤ 3000 m
Application example		V	600	CAT III, PD 2, according to UL 508

2. STK-10PL Electrical performance

Condition: T_A = 25°C, Vcc = 5 V (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_pn	A		10		
Primary current measuring range	I_pm	A	-25		25	
Supply voltage	Vcc	V	4.75	5	5.25	
Current consumption	Icc	mA		5	10	
Reference voltage	Vref	V	2.48	2.5	2.52	Output function
Rated output voltage	V_FS	V		0.8		(Vout - Vref) @ I_pn
Internal output resistance	R_out	Ω		1		Output
Quiescent voltage	Voff	V	2.48	2.5	2.52	Vout @ 0 A
Electrical offset voltage	Voe	mV	-10		10	(Vout - Vref) @ 0 A
Temperature drift of Voe	Voe_TRange	%V_FS	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I_om	A	-0.25		0.25	@ ±10 x I_pn
Theoretical gain	G_th	mV/A		80		800 mV @ I_pn
Error of gain	Err_G	%G_th		±0.5		Trimmed in the factory @ 25°C
Temperature drift of gain	G_TR	%G_th	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L_pn	%I_pn	-0.5		0.5	±I_pn
Linearity error @ I_pm	Non-L_pm	%I_pm	-1		1	±I_pm
Reaction time	t_ra	μs		0.5		@ 10% of I_pn
Step response time	t_res	μs		1.5		@ 90% of I_pn
Delay time	t_delay	μs		1		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	Vnoise	mVpp		15 25		
DC ~ 10 kHz						
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_pn	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I_pn	-3		3	-40°C ~ 105°C

3. STK-16PL Electrical performance

Condition: T_A = 25°C, Vcc = 5 V (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_pn	A		16		
Primary current measuring range	I_pm	A	-40		40	
Supply voltage	Vcc	V	4.75	5	5.25	
Current consumption	Icc	mA		5	10	
Reference voltage	Vref	V	2.48	2.5	2.52	Output function
Rated output voltage	V_FS	V		0.8		(Vout - Vref) @ I_pn
Internal output resistance	R_out	Ω		1		Output
Quiescent voltage	Voff	V	2.48	2.5	2.52	Vout @ 0 A
Electrical offset voltage	Voe	mV	-10		10	(Vout - Vref) @ 0 A
Temperature drift of Voe	Voe_TRange	%V_FS	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I_om	A	-0.25		0.25	@ ±10 x I_pn
Theoretical gain	G_th	mV/A		50		800 mV @ I_pn
Error of gain	Err_G	%G_th		±0.5		Trimmed in the factory @ 25°C
Temperature drift of gain	G_TR	%G_th	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L_pn	%I_pn	-0.5		0.5	±I_pn
Linearity error @ I_pm	Non-L_pm	%I_pm	-1		1	±I_pm
Reaction time	t_ra	μs		0.5		@ 10% of I_pn
Step response time	t_res	μs		1.5		@ 90% of I_pn
Delay time	t_delay	μs		1		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	Vnoise	mVpp		15 25		
DC ~ 10 kHz						
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_pn	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I_pn	-3		3	-40°C ~ 105°C

4. STK-20PL Electrical performance

Condition: T_A = 25°C Vcc = 5 V (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_pn	A		20		
Primary current measuring range	I_pm	A	-50		50	
Supply voltage	Vcc	V	4.75	5	5.25	
Current consumption	Icc	mA		5	10	
Reference voltage	Vref	V	2.48	2.5	2.52	Output function
Rated output voltage	V_FS	V		0.8		(Vout - Vref) @ I_pn
Internal output resistance	R_out	Ω		1		Output
Quiescent voltage	Voff	V	2.48	2.5	2.52	Vout @ 0 A
Electrical offset voltage	Voe	mV	-10		10	(Vout - Vref) @ 0 A
Temperature drift of Voe	Voe_TRange	%V_FS	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I_om	A	-0.25		0.25	@ ±10 x I_pn
Theoretical gain	G_th	mV/A		40		800 mV @ I_pn
Error of gain	Err_G	%G_th		±0.5		Trimmed in the factory @ 25°C
Temperature drift of gain	G_TR	%G_th	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L_pn	%I_pn	-0.5		0.5	±I_pn
Linearity error @ I_pm	Non-L_pm	%I_pm	-1		1	±I_pm
Reaction time	t_ra	μs		0.5		@ 10% of I_pn
Step response time	t_res	μs		1.5		@ 90% of I_pn
Delay time	t_delay	μs		1		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	Vnoise	mVpp		12		
DC ~ 10 kHz				17		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_pn	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I_pn	-3		3	-40°C ~ 105°C

5. STK-32PL Electrical performance

Condition: T_A = 25°C Vcc = 5 V (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_pn	A		32		
Primary current measuring range	I_pm	A	-80		80	
Supply voltage	Vcc	V	4.75	5	5.25	
Current consumption	Icc	mA		5	10	
Reference voltage	Vref	V	2.48	2.5	2.52	Output function
Rated output voltage	V_FS	V		0.8		(Vout - Vref) @ I_pn
Internal output resistance	R_out	Ω		1		Output
Quiescent voltage	Voff	V	2.48	2.5	2.52	Vout @ 0 A
Electrical offset voltage	Voe	mV	-10		10	(Vout - Vref) @ 0 A
Temperature drift of Voe	Voe_TRange	%V_FS	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I_om	A	-0.25		0.25	@ ±10 x I_pn
Theoretical gain	G_th	mV/A		25		800 mV @ I_pn
Error of gain	Err_G	%G_th		±0.5		Trimmed in the factory @ 25°C
Temperature drift of gain	G_TR	%G_th	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L_pn	%I_pn	-0.5		0.5	±I_pn
Linearity error @ I_pm	Non-L_pm	%I_pm	-1.0		1.0	±I_pm
Reaction time	t_ra	μs		0.5		@ 10% of I_pn
Step response time	t_res	μs		1.5		@ 90% of I_pn
Delay time	t_delay	μs		1		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	Vnoise	mVpp		12		
DC ~ 10 kHz				17		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_pn	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I_pn	-3		3	-40°C ~ 105°C

6. STK-40PL Electrical performance

Condition: T_A = 25°C Vcc = 5 V (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_pn	A		40		
Primary current measuring range	I_pm	A	-100		100	
Supply voltage	Vcc	V	4.75	5	5.25	
Current consumption	Icc	mA		5	10	
Reference voltage	Vref	V	2.48	2.5	2.52	Output function
Rated output voltage	V_FS	V		0.8		(Vout - Vref) @ I_pn
Internal output resistance	R_out	Ω		1		Output
Quiescent voltage	Voff	V	2.48	2.5	2.52	Vout @ 0 A
Electrical offset voltage	Voe	mV	-10		10	(Vout - Vref) @ 0 A
Temperature drift of Voe	Voe_TRange	%V_FS	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I_om	A	-0.25		0.25	@ ±10 x I_pn
Theoretical gain	G_th	mV/A		20		800 mV @ I_pn
Error of gain	Err_G	%G_th		±0.5		Trimmed in the factory @ 25°C
Temperature drift of gain	G_TR	%G_th	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L_pn	%I_pn	-0.5		0.5	±I_pn
Linearity error @ I_pm	Non-L_pm	%I_pm	-1		1	±I_pm
Reaction time	t_ra	μs		0.5		@ 10% of I_pn
Step response time	t_res	μs		1.5		@ 90% of I_pn
Delay time	t_delay	μs		1		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	Vnoise	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_pn	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I_pn	-3		3	-40°C ~ 105°C

7. STK-50PL Electrical performance

Condition: T_A = 25°C Vcc = 5 V (Except special instructions)

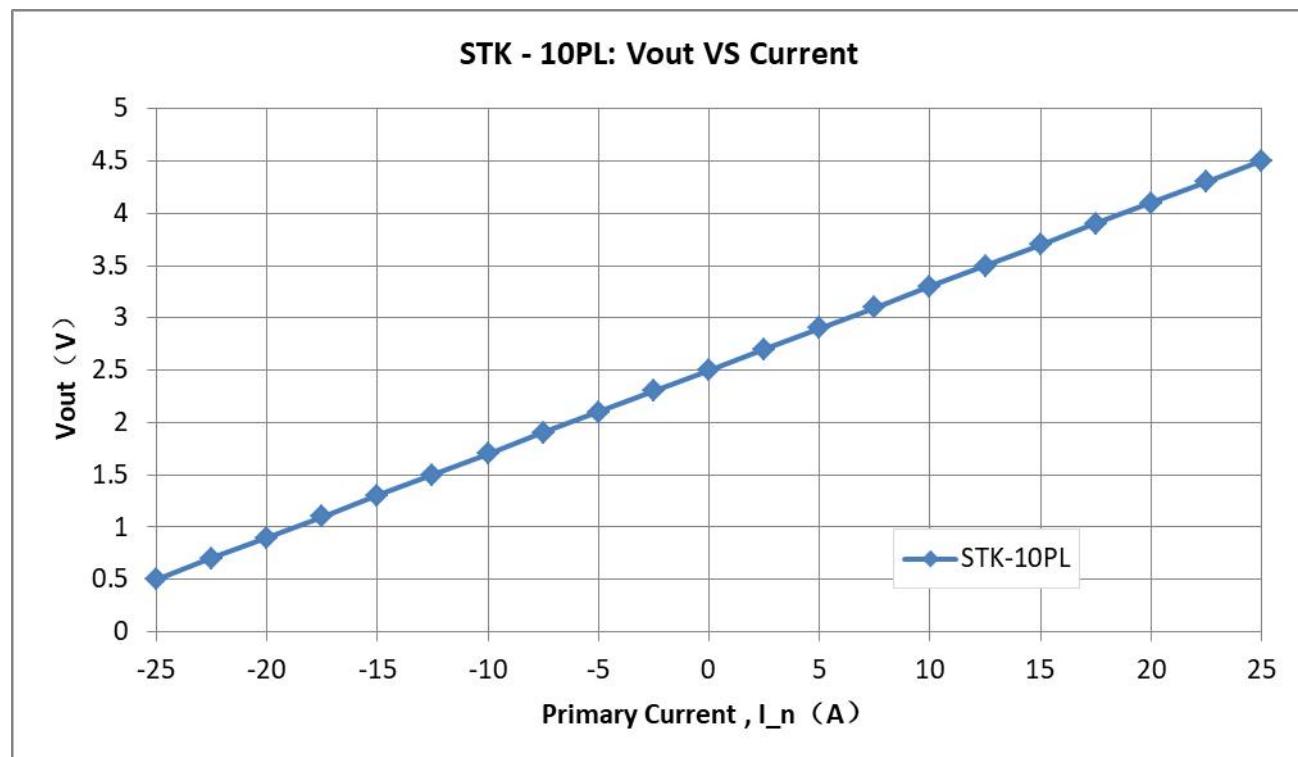
Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_pn	A		50		
Primary current measuring range	I_pm	A	-125		125	
Supply voltage	Vcc	V	4.75	5	5.25	
Current consumption	Icc	mA		5	10	
Reference voltage	Vref	V	2.48	2.5	2.52	Output function
Rated output voltage	V_FS	V		0.8		(Vout - Vref) @ I_pn
Internal output resistance	R_out	Ω		1		Output
Quiescent voltage	Voff	V	2.48	2.5	2.52	Vout @ 0 A
Electrical offset voltage	Voe	mV	-10		10	(Vout - Vref) @ 0 A
Temperature drift of Voe	Voe_TRange	%V_FS	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I_om	A	-0.25		0.25	@ ±10 x I_pn
Theoretical gain	G_th	mV/A		16		800 mV @ I_pn
Error of gain	Err_G	%G_th		±0.5		Trimmed in the factory @ 25°C
Temperature drift of gain	G_TR	%G_th	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L_pn	%I_pn	-0.5		0.5	±I_pn
Linearity error @ I_pm	Non-L_pm	%I_pm	-1.5		1.5	±I_pm
Reaction time	t_ra	μs		0.5		@ 10% of I_pn
Step response time	t_res	μs		1.5		@ 90% of I_pn
Delay time	t_delay	μs		1		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	Vnoise	mVpp		10 15		
DC ~ 10 kHz						
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_pn	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I_pn	-3		3	-40°C ~ 105°C

8. STK-50PL/R Electrical performance

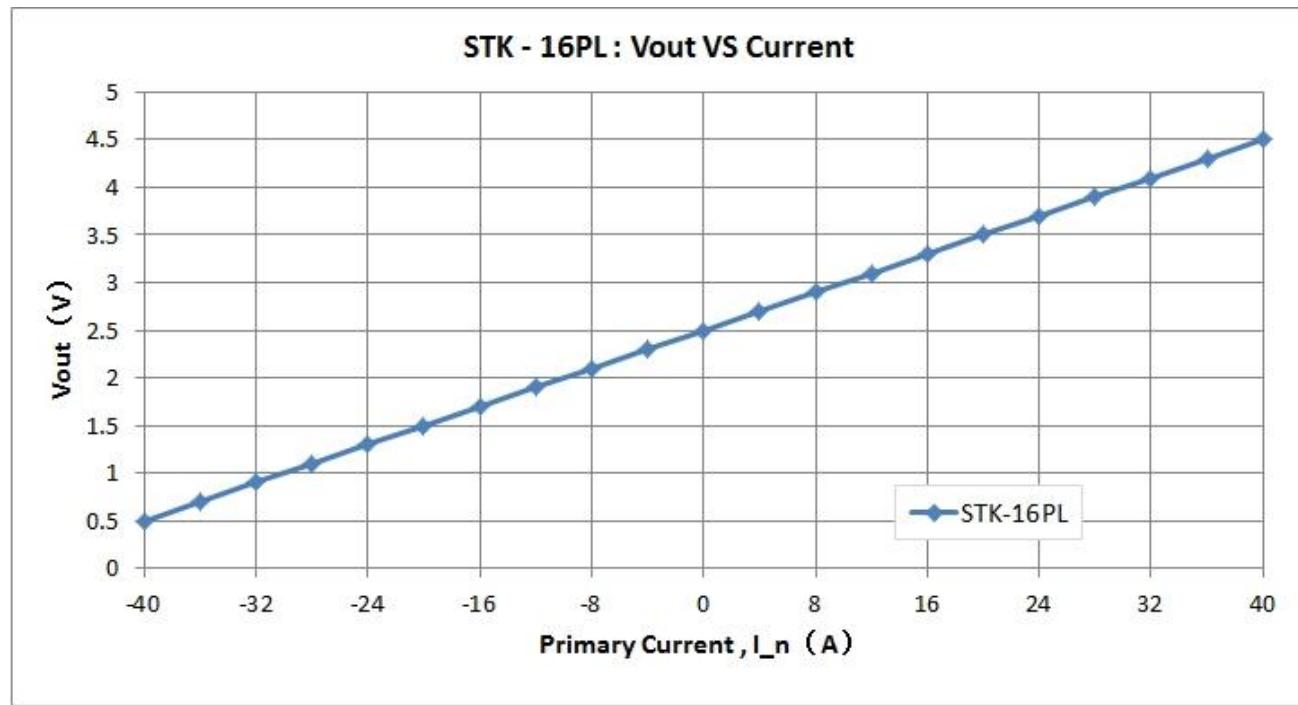
Condition: T_A = 25°C Vcc = 5 V (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_pn	A		50		
Primary current measuring range	I_pm	A	-170		170	
Supply voltage	Vcc	V	4.75	5	5.25	
Current consumption	Icc	mA		5	10	
Reference voltage	Vref	V	2.48	2.5	2.52	Output function
output voltage@ I_pm	V_FS	V		2		(Vout - Vref)@ I_pm
Internal output resistance	R_out	Ω		1		Output
Quiescent voltage	Voff	V	2.48	2.5	2.52	Vout @ 0 A
Electrical offset voltage	Voe	mV	-10		10	(Vout – Vref) @ 0 A
Temperature drift of Voe	Voe_TRange	%V_FS	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I_om	A	-0.25		0.25	@ ±10 x I_pn
Theoretical gain	G_th	mV/A		11.76		2V @ I_pm
Error of gain	Err_G	%G_th		±0.5		Trimmed in the factory @ 25°C
Temperature drift of gain	G_TR	%G_th	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L_pn	%I_pn	-0.5		0.5	±I_pn
Linearity error @ I_P = 150A	Non-L_p	%I_pm	-1.5		1.5	±150A
Linearity error @ I_pm	Non-L_pm	%I_pm	-5		5	±I_pm
Reaction time	t_ra	μs		0.5		@ 10% of I_pm
Step response time	t_res	μs		1.5		@ 90% of I_pm
Delay time	t_delay	μs		1		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise DC ~ 10 kHz	Vnoise	mVpp		10		
DC ~ 100 kHz				15		
Accuracy @ 25°C	X	% of I_pn	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I_pn	-3		3	-40°C ~ 105°C

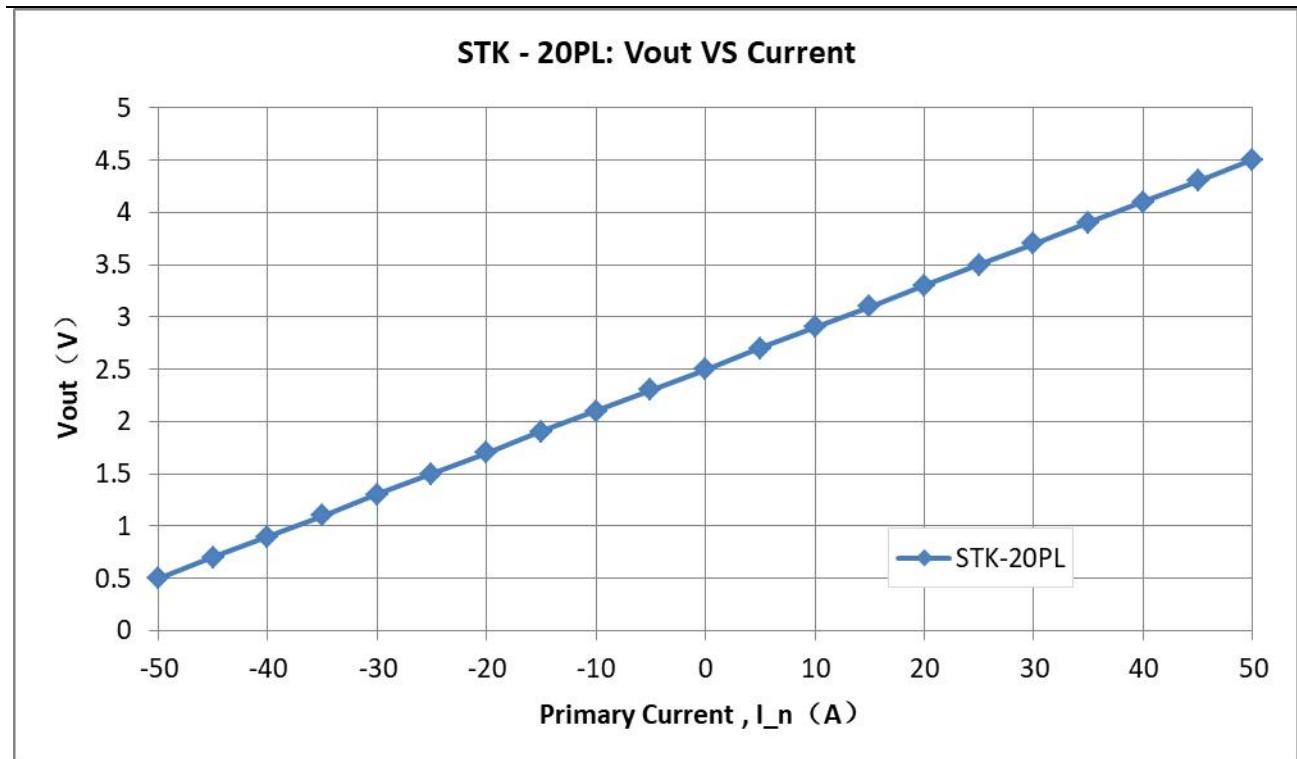
10. Output voltage VS primary current



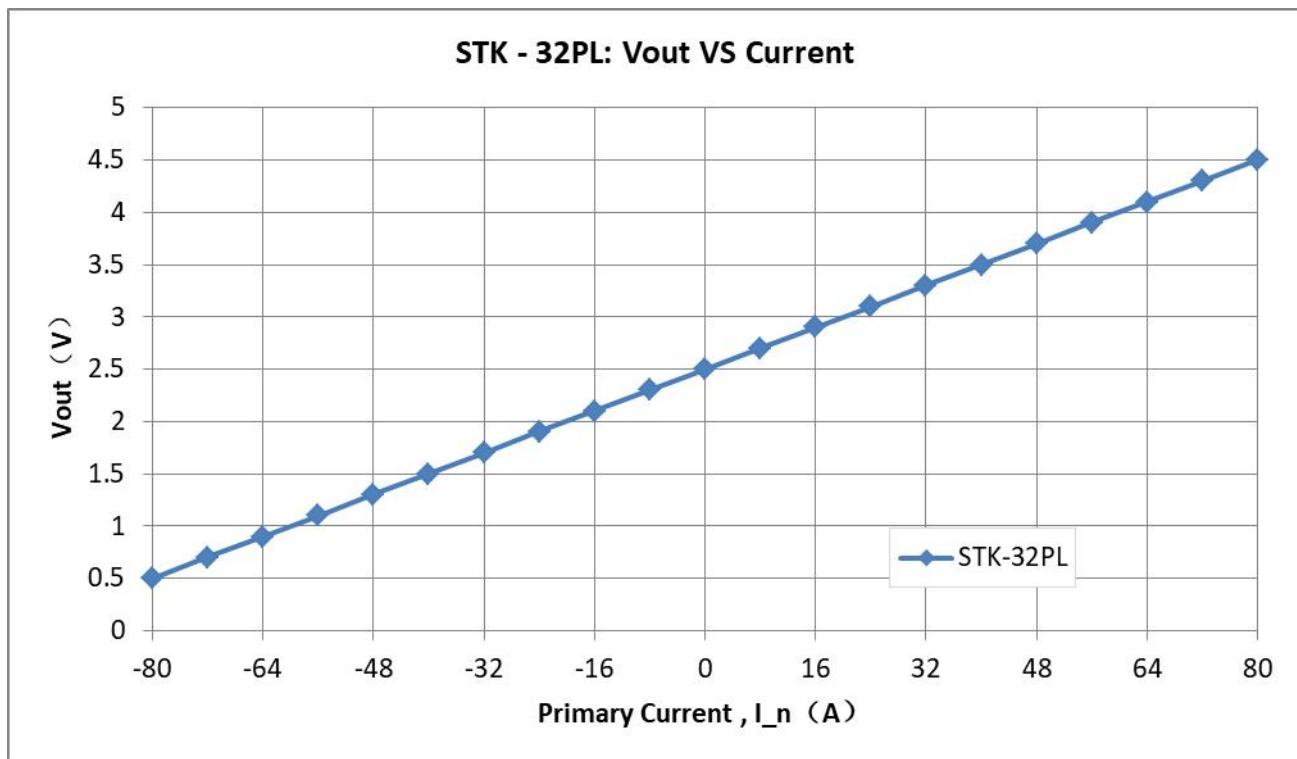
The dependence of V_{out} of STK-10PL on the primary current.



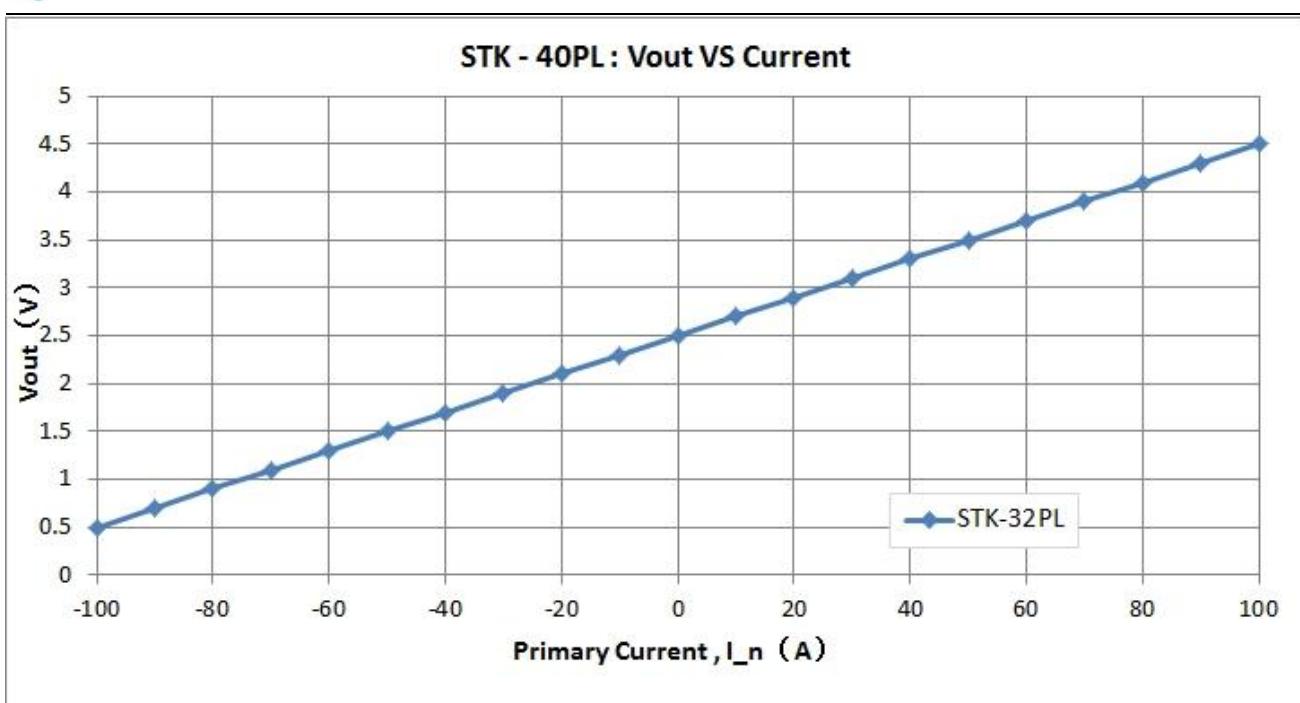
The dependence of V_{out} of STK-16PL on the primary current.



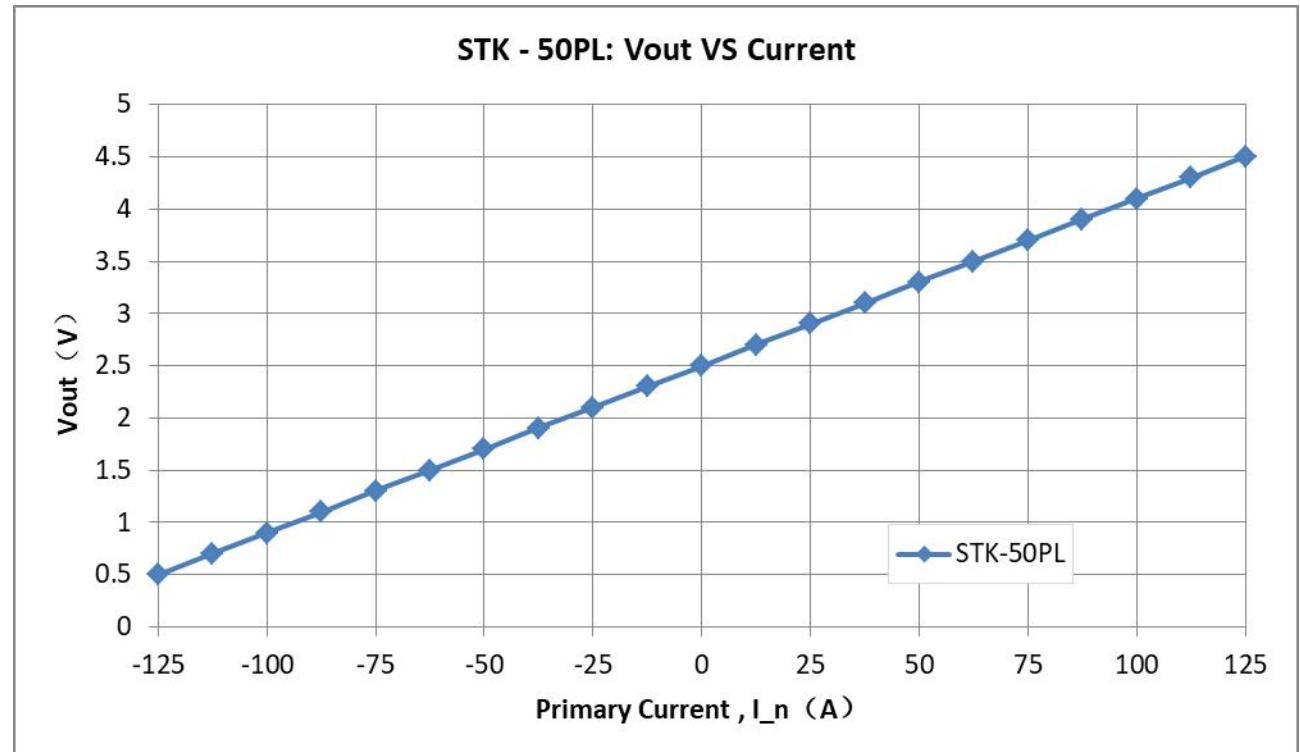
The dependence of V_{out} of STK-20PL on the primary current.



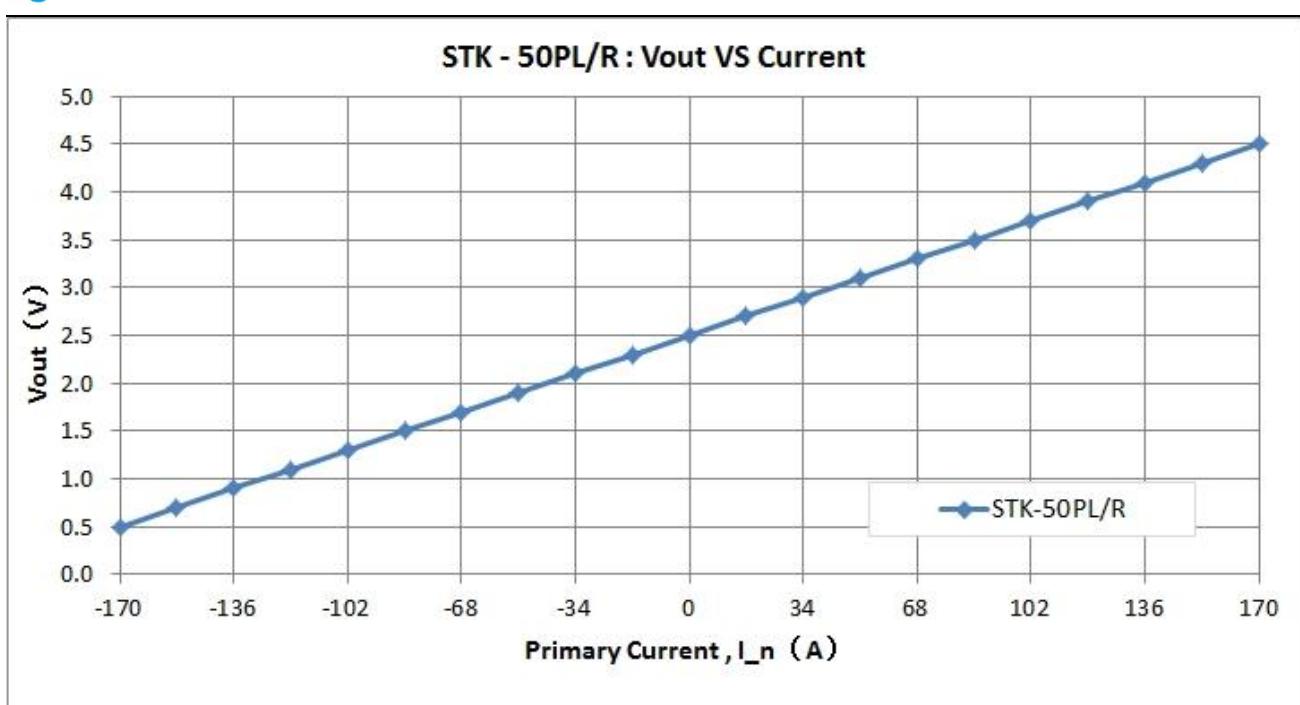
The dependence of V_{out} of STK-32PL on the primary current.



The dependence of V_{out} of STK-40PL on the primary current.

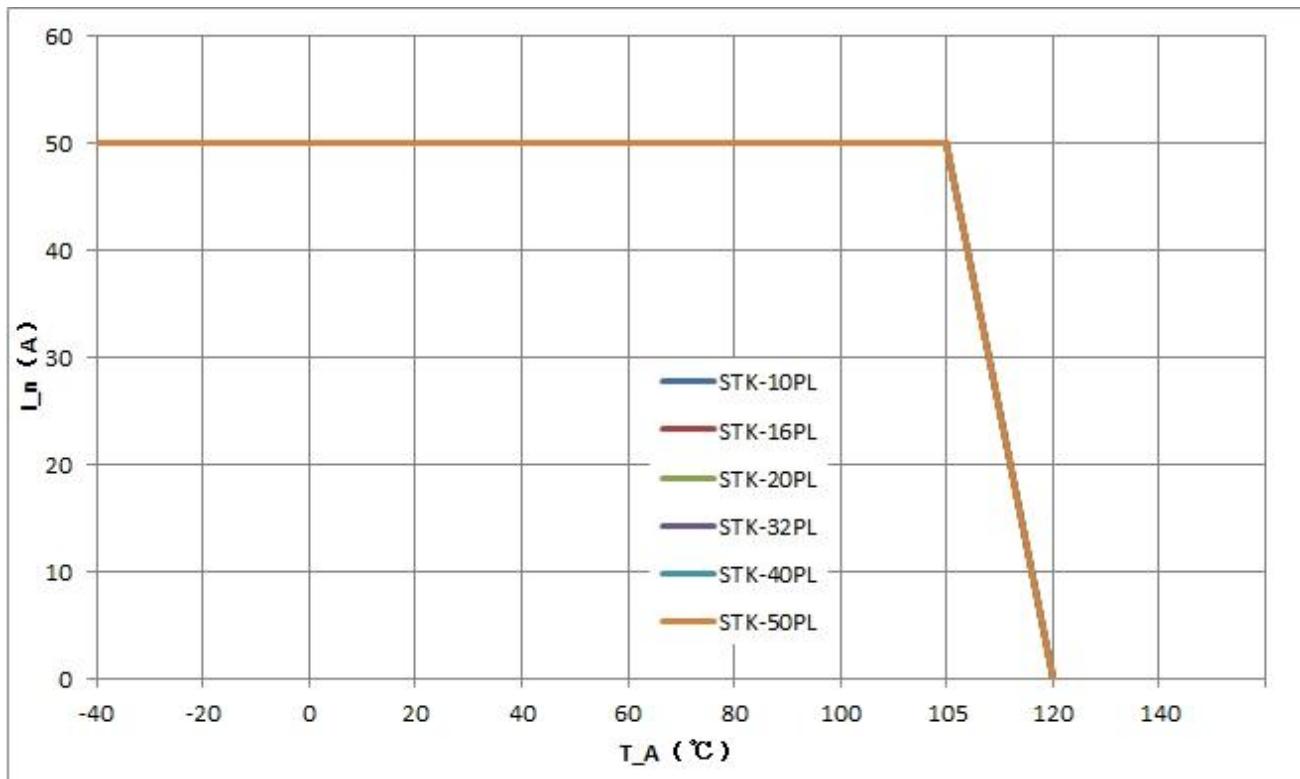


The dependence of V_{out} of STK-50PL on the primary current.



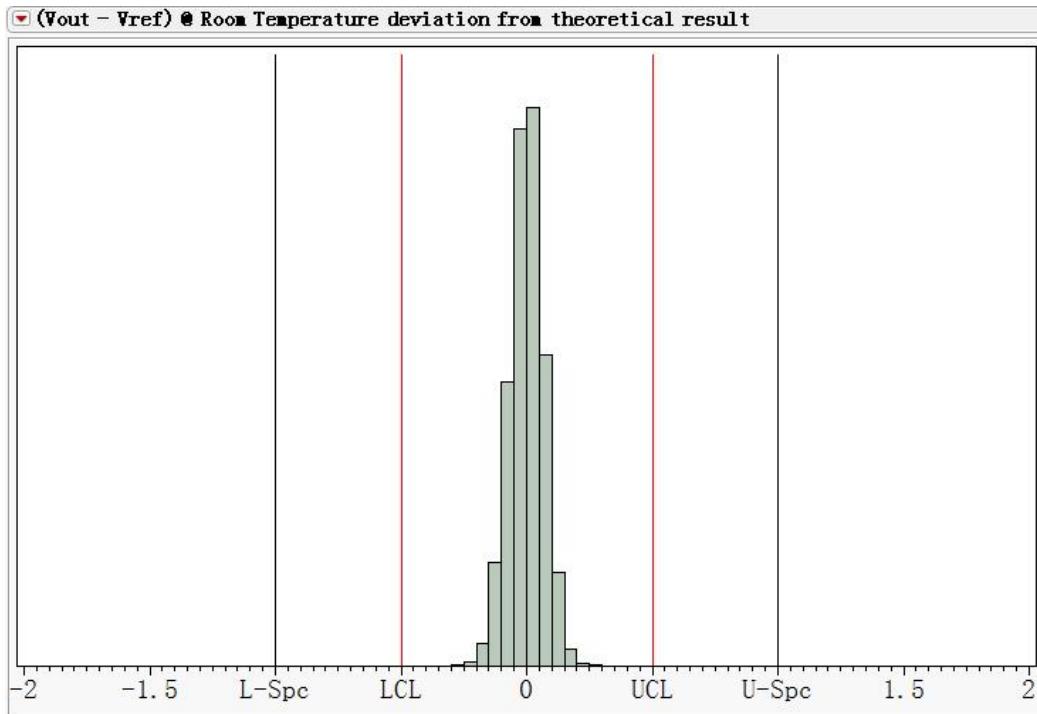
The dependence of Vout of STK-50PL/R on the primary current.

11. Maximum continues DC current



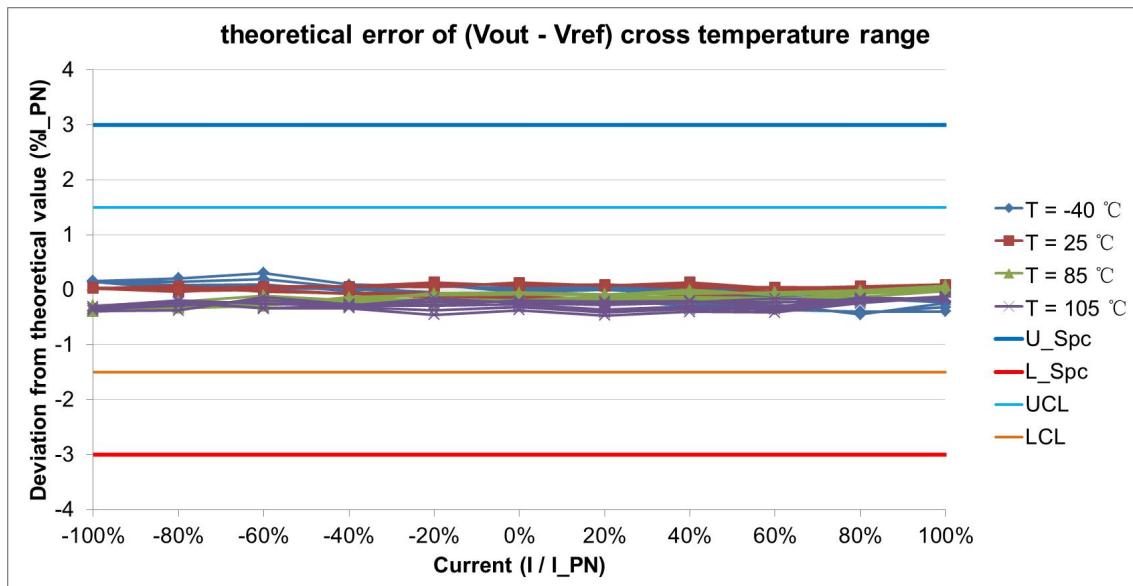
The dependence of maximum continues current of STK-PL current on the working temperature.

12. Accuracy characteristics in room temperature

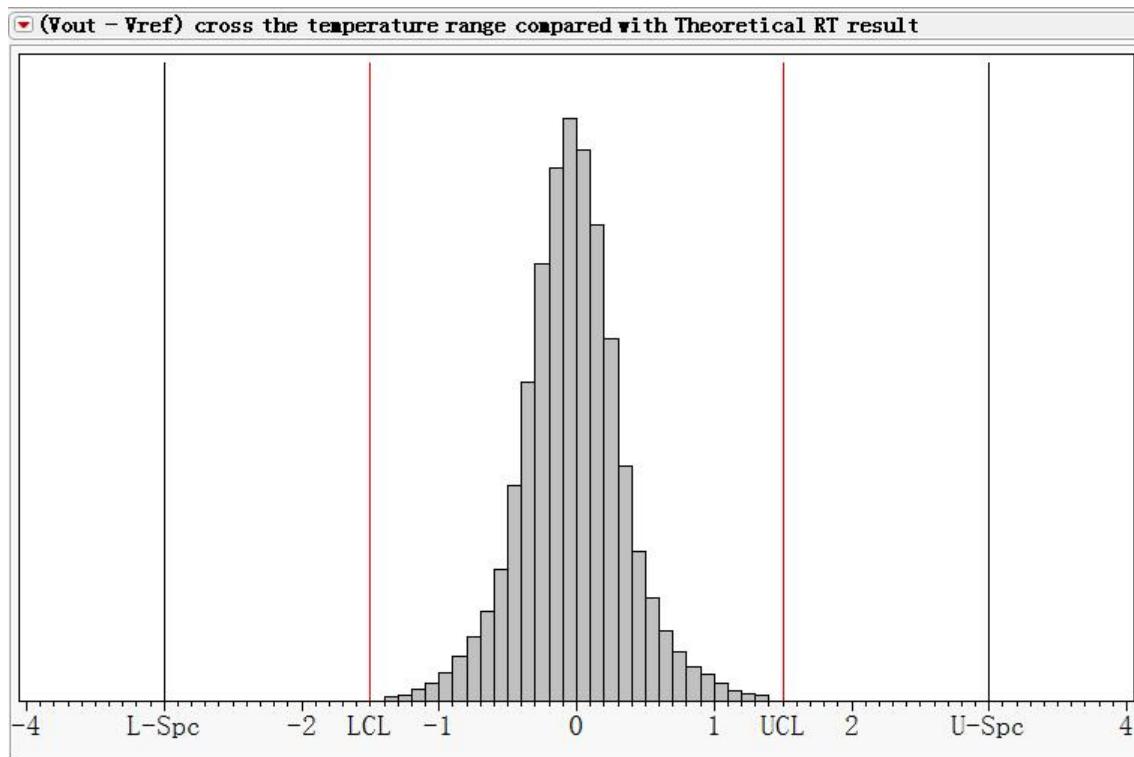


The error of STK-PL current sensor at 25°C compared with the standard output, $((V_{out} - V_{ref})_{measure} @ I_n @ 25^\circ C - V_{oe}@25^\circ C - G_{th} * I_n) / V_{FS}$. V_{out} represents voltage of V_{out} , V_{ref} the voltage of V_{ref} , I_n the primary current, V_{oe} the $(V_{out} - V_{ref})@0A$, G_{th} the theoretical gain, V_{FS} the rated output voltage.

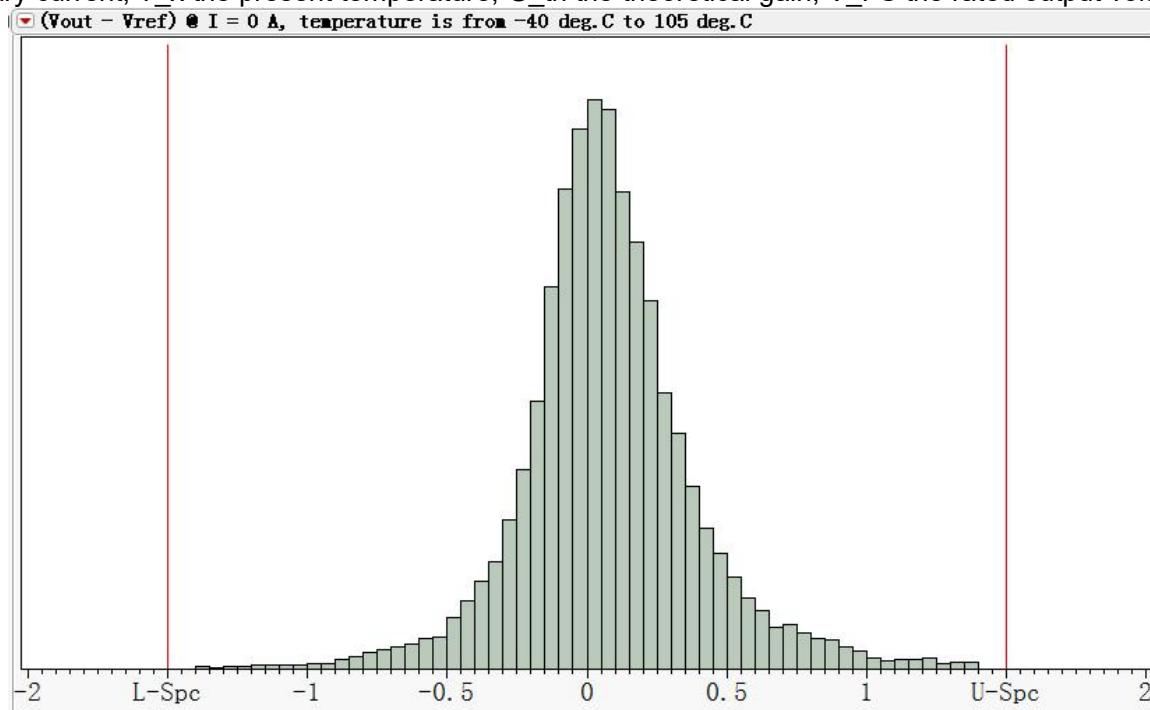
13. Accuracy cross temperature



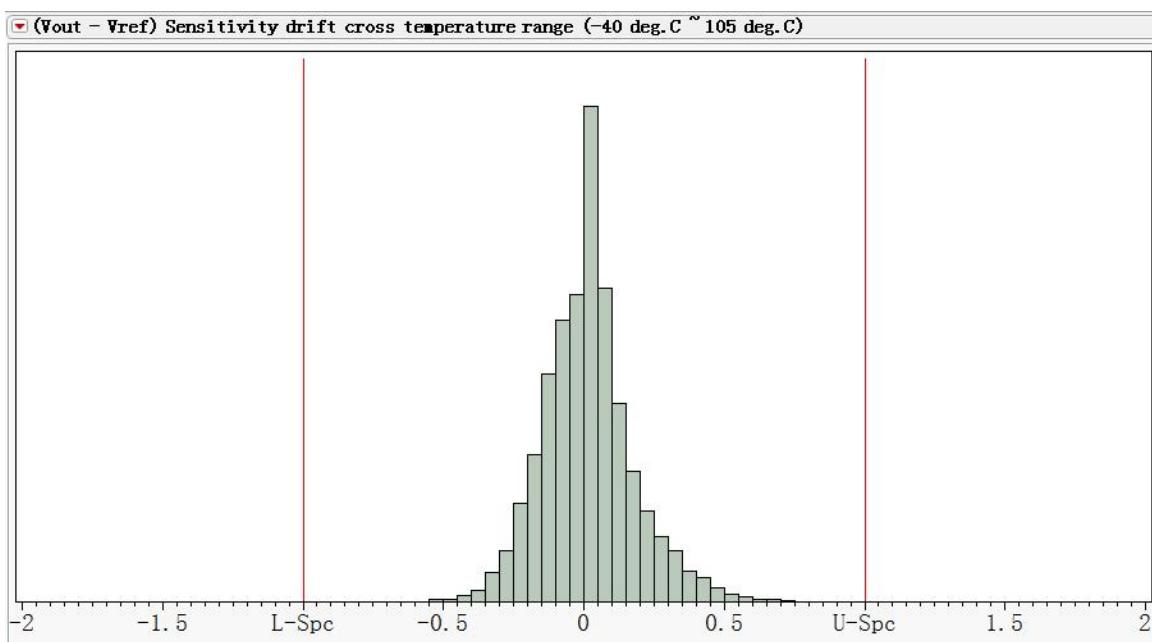
The error of STK-PL current sensor at -40 °C ~105 °C compared with the standard output at room temperature, $((V_{out} - V_{ref})_{measure} @ I_n @ T_x - V_{oe}@ T_x - G_{th} * I_n) / V_{FS}$. Where, V_{out} represents voltage of V_{out} , V_{ref} the voltage of V_{ref} , I_n the primary current, T_x the present temperature, V_{oe} the $(V_{out} - V_{ref})@0A$, G_{th} the theoretical gain, V_{FS} the rated output voltage.



The error of STK-PL output ($V_{out} - V_{ref}$) current sensor at $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$ compared with the standard output ($V = G_{th} * I_n$), $((V_{out} - V_{ref}) @ I_n @ T_x - G_{th} * I_n) / V_{FS}$, Where, I_n represents present primary current, T_x the present temperature, G_{th} the theoretical gain, V_{FS} the rated output voltage.

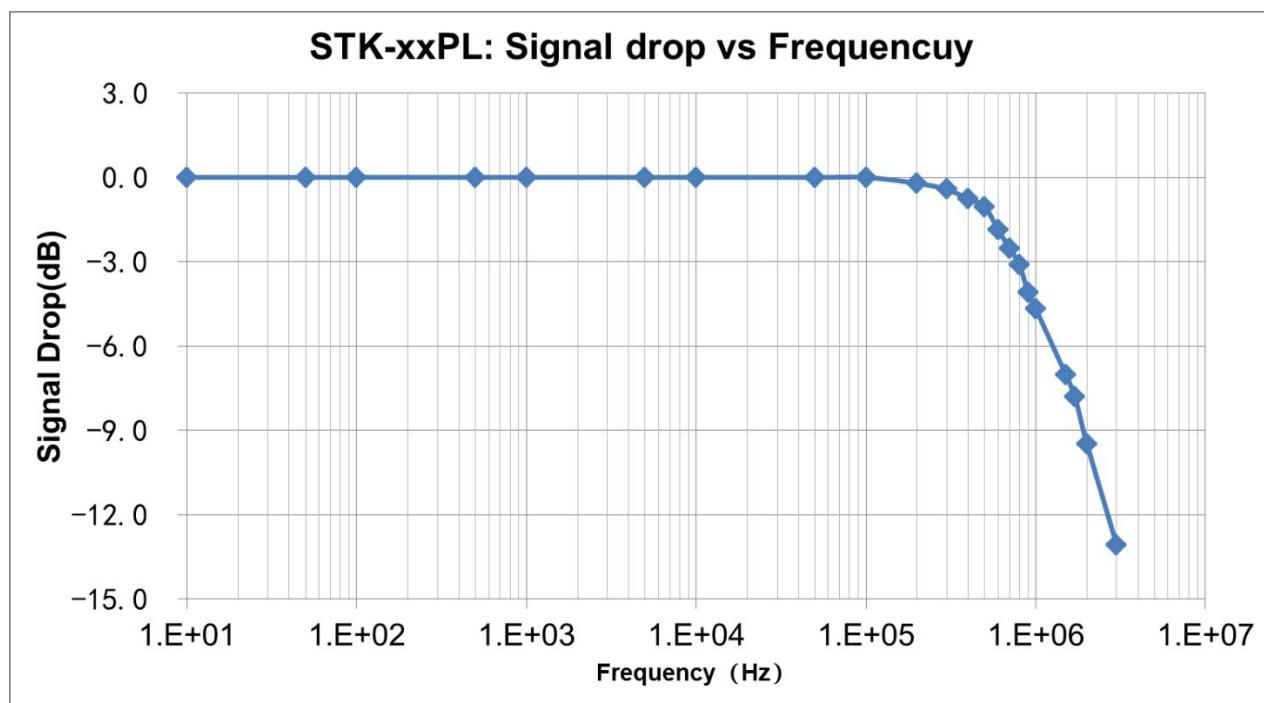


Temperature drift of Voe, $\text{Voe_TRange} = (\text{Voe} @ T_x - \text{Voe} @ 25^{\circ}\text{C}) / V_{FS}$. T_x represents present temperature, V_{FS} the rated output voltage.



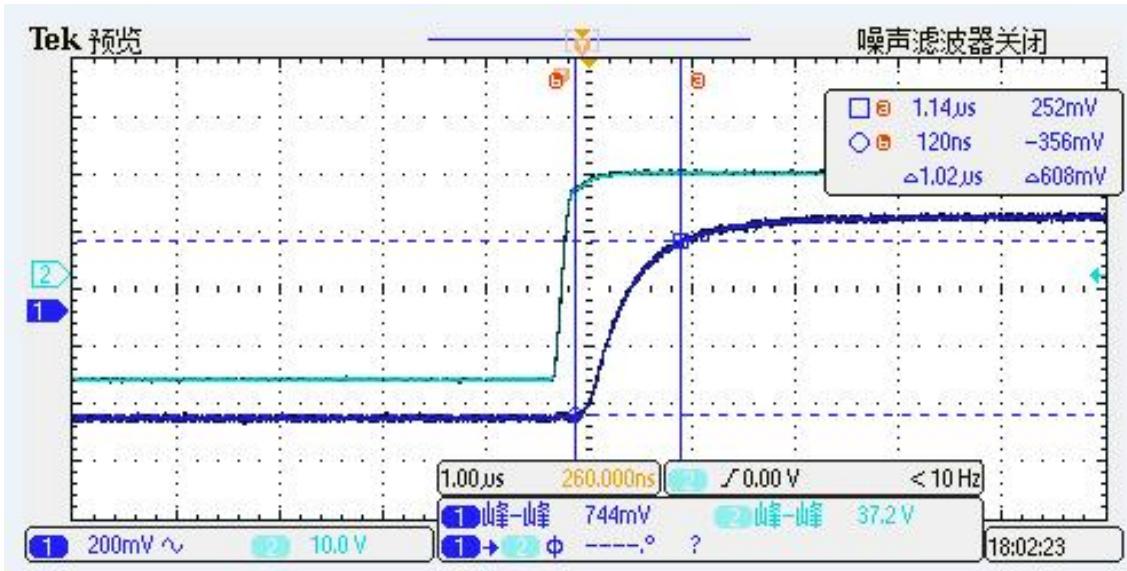
Error of gain, $\text{Err_G} = (((\text{Vout} - \text{Vref}) @ \text{I_pn} - (\text{Vout} - \text{Vref}) @ (-\text{I_pn})) / 2) - \text{V_FS} / \text{V_FS}$. Where I_pn represents the rated current, $-\text{I_pn}$ the reversed rated current.

14. Frequency response and bandwidth



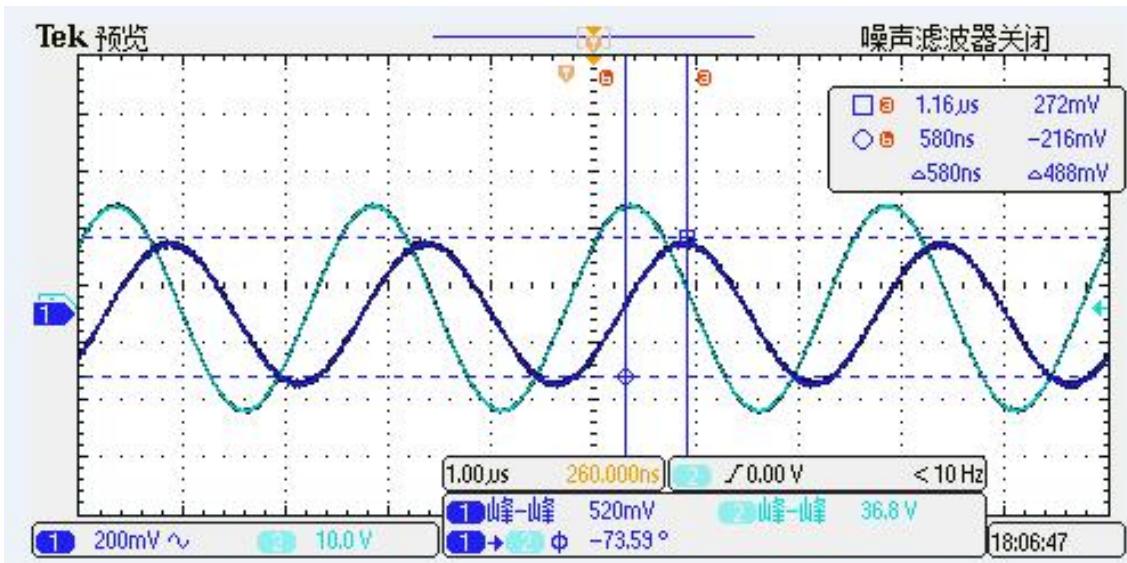
The frequency bandwidth of STK-PL series current sensor. The bandwidth of current sensor is DC ~ 400 kHz (-3dB).

15. Step response time



The typical frequency response of STK-xxPL current sensor. The response time from 90% of the primary current (light blue) to 90% of the secondary output (dark blue) is less than 1.5 μ s

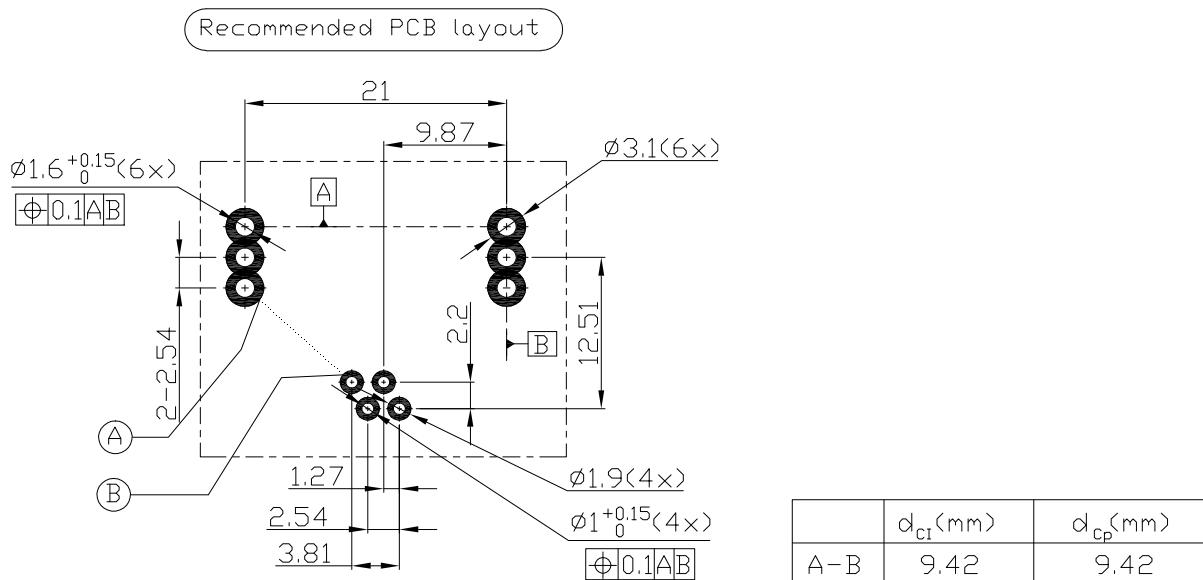
16. Frequency delay performance



When testing 400 kHz sine wave, the typical result of STK-xxPL current sensor's output. The response time from the primary current (light blue) to the secondary output (dark blue) is less than 1 μ s.

17. Recommended PCB layout

Installation of view: overlooking (unit: mm)



1. Installing angle: Overlook (observe from the side of installing transducer)
2. Recommended bore diameter of primary current line, (diameter of primary current \times 1.2) mm
3. Recommended bore diameter of secondary current line, (diameter of secondary current \times 1.2) mm
4. The maximum thickness of PCB is 2.5 mm
5. The curve of wave soldering: 260°C \times 10 s

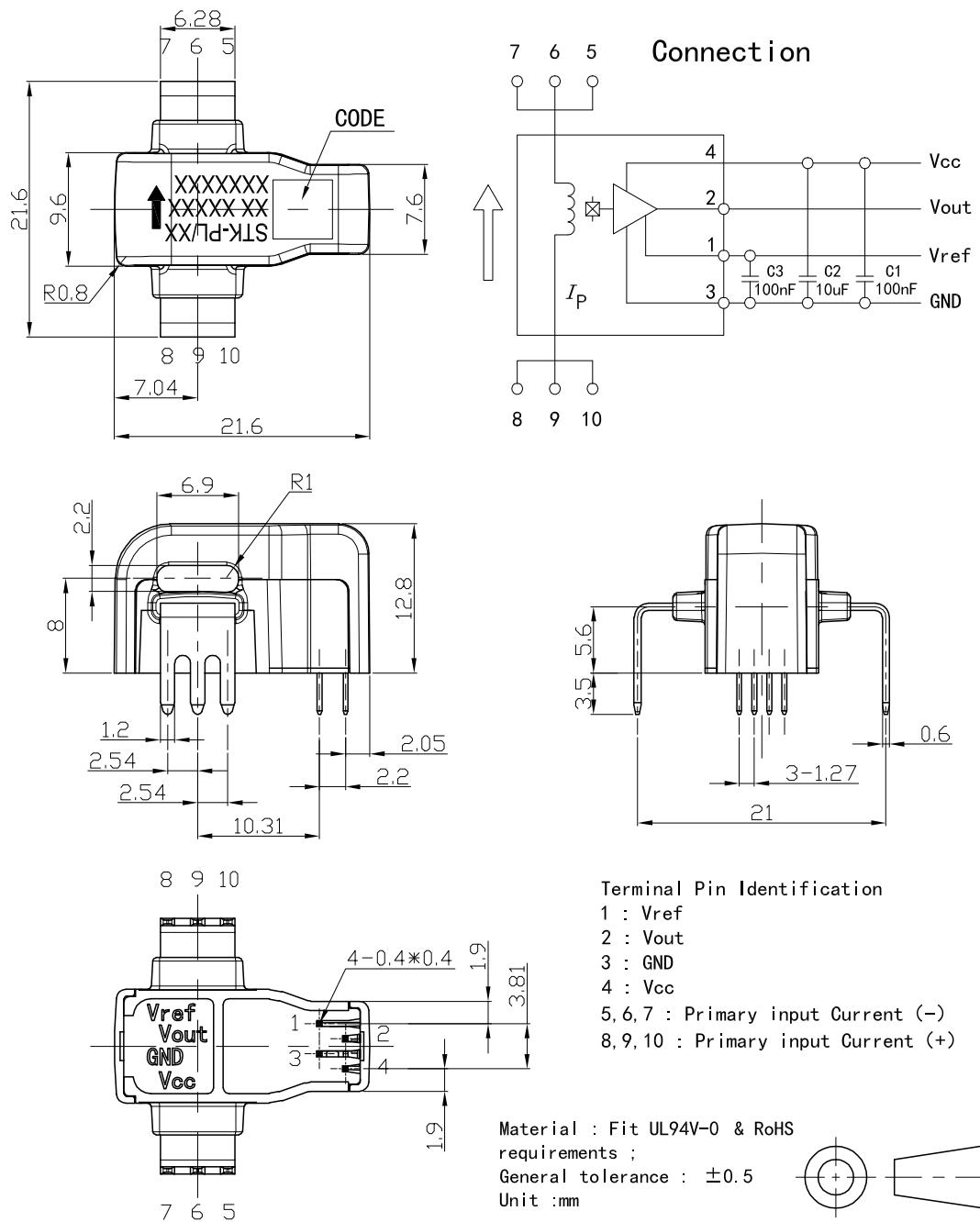


Security:

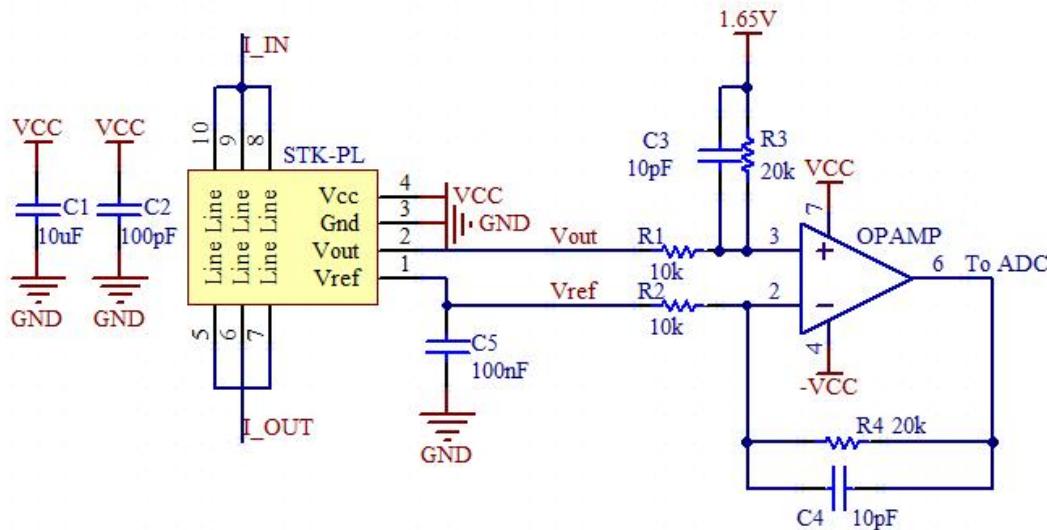
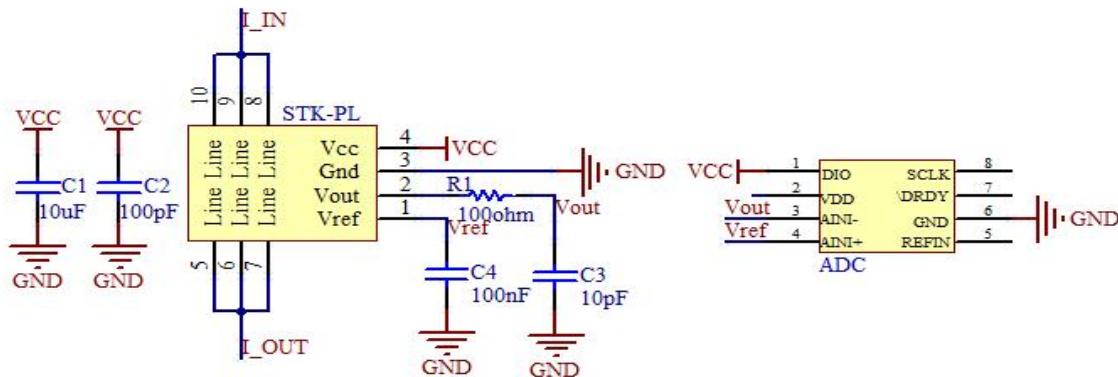
This current sensor must be used in limited-energy secondary circuit according to IEC 61010-1.

- This current sensor must be used in electric/electronic equipment with respect to appliance standards and safety requirement in accordance with the manufacture's operating instructions;
- When operating the current sensor, certain parts of the module can carry hazardous voltage;
- Failure to wiring as shown in the diagram will damage the current sensor;
- Ignoring this warning can lead to serious consequences.
- A protective housing or a additional shield could be used.
- Main supply must be able to disconnected.

18. Dimension & Pin definitions



19. Appendix: typical application circuit



R3 (kohm)	C3 (pF)	Theoretical -3dB $f = 1/(2\pi RC)$ (kHz)	Measured -3dB (kHz)
20	20	398	~ 400
20	81	98	~ 100
20	810	10	~ 10

The frequency characteristics of STK_PL series current sensor are not affected by the R-C setting (according to recommended R-C setting), therefore the active filter circuit or R-C circuit can be applied to modulate the sensor's frequency characteristics.

The signal input to ADC is $1.65 + R4/R2 \cdot (Vout - Vref)$ with the conditions: $R1 = R2$, $R3 = R4$, $C3 = C4$.